SMD NPN Transistor





Features:

- Silicon planar epitaxial transistors
- General purpose NPN transistors



Pin Configuration:

- 1. Base
- 2. Emitter

3. Collector

Absolute Maximum Ratings:

Description	Symbol		BC847C	Units
Collector-Emitter Voltage ($V_{BE} = 0$)	V _{CES}		50	V
Collector-Emitter Voltage (Open Base)	V _{CEO}	Max.	45	
Collector Current (Peak Value)	I _{CM}		200	mA
Total Power Dissipation up to $T_a = 25^{\circ}C$	P _{tot}		250	mW
Junction Temperature	Τ _j		150	°C
Small-Signal Current Gain $I_{c} = 2mA; V_{cE} = 5V; f = 1kHz$	h _{fe}	Min	125	-
Transition Frequency at f = 100MHz $I_{C} = 10mA; V_{CE} = 5V$	f _T	IVIII1.	>100	MHz
Noise Figure at $R_s = 2kW$ $I_c = 200mA; V_{CE} = 5V$ f = 1kHz; B = 200Hz	F	Тур.	2	dB

Ratings (at T_A = 25°C unless otherwise specified)

Description	Symbol		BC847B	Units
Collector-Base Voltage (Open Emitter)	V _{CBO}	Max.	50	V
Collector-Emitter Voltage ($V_{BE} = 0$)	V _{CES}			
Collector-Emitter Voltage (Open Base)	V _{CEO}		45	
Emitter-Base Voltage (Open Collector)	V _{EBO}		6	
Collector Current (DC)	Ι _c		100	mA

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Ratings (at $T_A = 25^{\circ}C$ unless otherwise specified)

Description	Symbol		BC847B	Units
Collector Current (Peak Value)	I _{CM}		200	mA
Emitter Current (Peak Value)	-I _{EM}	Max.		
Base Current (Peak Value)	I _{BM}			
Total Power Dissipation upto T _a : 25°C	P _{tot}		250	mW
Storage Temperature	T _{stg}	- Max.	-55 to +150	°C
Junction Temperature	Т _ј		150	
Thermal Resistance				
From Junction to Ambient	R _{th (j-a)}	=	500	K/W

Characteristics ($T_j = 25^{\circ}C$ unless otherwise specified)

Collector Cut off Current $I_E = 0; V_{CB} = 30V$ $I_E = 0; V_{CB} = 30V; T_j = 150^{\circ}C$	I _{сво}	<	15 5	nA μA
Base-Emitter Voltage I _C = 2mA; V _{CE} = 5V	V _{BE}	Тур.	660	
$I_{c} = 10 \text{mA}; V_{cE} = 5 \text{V}$	V _{BE}	<	580 to 700 770	
Saturation Voltage	V _{CE (sat)}	Тур.	90	mV
I _C = 10mA; I _B = 0.5mA I _C = 100mA; IB = 5mA	V _{BE (sat)} V _{CE (sat)} V _{BE (sat)}	< Typ. Typ. < Typ.	250 700 200 600 900	
Collector Capacitance at f = 1MHz $I_E = I_e = 0; V_{CB} = 10V$	C _C	Тур.	2.5	pF
Transition Frequency at f = 100MHz I_{C} = 10mA; V_{CE} = 5V	f _T	>	100	MHz
Noise Figure at $R_s = 2KW$ $I_c = 200\mu A; V_{CE} = 5V;$ f = 1kHz; B = 200Hz	F	Тур. Max.	2 10	dB
DC Current Gain $I_{C} = 10mA; V_{CE} = 5V$ $I_{C} = 2mA; V_{CE} = 5V$	h _{FE}	Тур. > Тур. <	270 420 520 800	-
Small Signal Current Gain at f = 1 kHz $I_{C} = 2mA; V_{CE} = 5V$	h _{fe}	Min. Max.	125 900	-

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SMD NPN Transistor

multicomp



Pin Configuration:

- 1. Base
- 2. Emitter
- 3. Collector

Dimensions : Millimetres

Part Number Table

Description	Part Number		
Transistor, NPN, SOT-23	BC847C		

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